## NSN 5961-00-024-0406

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Function For Which Designed:
Transient suppressor
Component Name And Quantity:
6 semiconductor device diode
Semiconductor Material:
Silicon all semiconductor device diode
Voltage Rating In Volts Per Characteristic:
180.0 regulator voltage all semiconductor device diode and 250.0 regulator voltage all semiconductor device diode
Current Rating Per Characteristic:
50.00 microamperes forward current, average peak all semiconductor device diode
Power Rating Per Characteristic:
350.0 watts small-signal input power, common-collector preset all semiconductor device diode
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Special Features:
All semiconductor device diode junction pattern arrangement: pn
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig: